

APSEMI PhotoRelays

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APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load •
- switching
- Small package size

Function

APSEMI PhotoRelays operate by taking a low level input current (<5mA) that energizes an input Infrared LED, which is optically-coupled to a Photo-diode array chip. This IC in turn generates a photo voltage that powers two MOSFETs typically connected in a source-to-source con guration, allowing for both AC and DC output loads. Photorelay basically move photons to accomplish their switching function, they incur no mechanical wear and tear, providing consistent reliable switching.

Applications

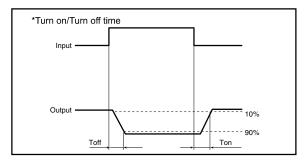
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching .
- Multiplexers
- Meter reading systems .
- Data acquisition
- Medical equipment .
- Battery monitoring
- I/O Sub-Systems

- Robotics Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

6	Category -	Output Rating		Pookogo	Part No.	Packing Quantity	
Ca		Load Voltage	Load Current	Package	Fait NO.	Packing Quantity	
A	C/DC	60V	0.5A	SOP-4	APY412GS	2000pcs /reel	



Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Value	Units	Note
	Continuous LED Current	F	50	mA	
Input	Peak LED Current	FP	500	mA	f=100Hz, duty=1%
'	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pin	75	mW	
	Load Voltage	VL	60	V(AC peak or DC)	
	Load Current	L	0.5	А	
Output	Peak Load Current	Peak	0.6	А	100ms(1 pulse)
	Output Power Dissipation	Pout	300	mW	
Total Power Dissipation I/O Breakdown Voltage Operating Temperature Storage Temperature Pin Soldering Temperature		Рт	350	mW	
		Vi/o	2500	Vrms	RH=60%, 1min
		Topr	-40 to 85	C°	
		Tstg	-40 to 100	°C	
		T _{sol}	260	°C	10 sec max.

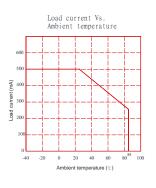
Electrical Characteristics (Ta = 25°C)

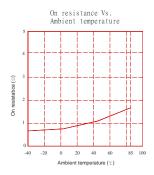
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
	LED Forward Voltage	VF		1.2	1.4	V	l⊧=10mA
	Operation LED Current	Fon		0.5	3.0	mA	
Input	Recovery LED Current	Foff	0.1	0.4		mA	
	Recovery LED Voltage	VFoff	0.5			V	
	On-Resistance	Ron		0.8	1.5	Ω	l⊧=0mA,I⊾=100mA, Time to flow is within 1 sec.
Output	Off-State Leakage	Leak			1	uA	V₋=Rating
	Output Capacitance	Cout		165		pF	V∟=0, f=1MHz
Transmis	Turn-On Time	Ton		0.5	1.0	ms	l⊧=5mA, l∟=100mA,
sion	Turn-Off Time	T _{off}		0.25	2.0	ms	
	I/O Isolation Resistance	Ri⁄o	10 ¹⁰			Ω	DC500V
Coupled	I/O Capacitance	Ci/o		0.8	1.5	pF	f=1MHz

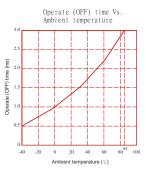
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

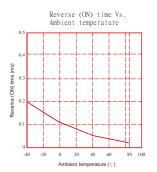
APSEMI

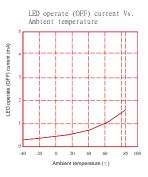
Engineering Data

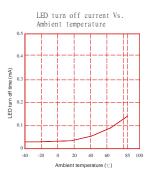








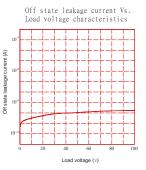


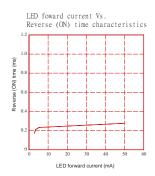


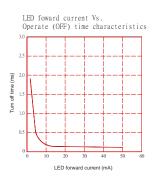
LED forward voltage Vs. Ambient temperature

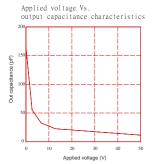


	Current. A	100 80 60 40		+ +
-5 -4	-3 -2 -	20 1 	2 3 Voltag	4 5 ge, V –
	1			



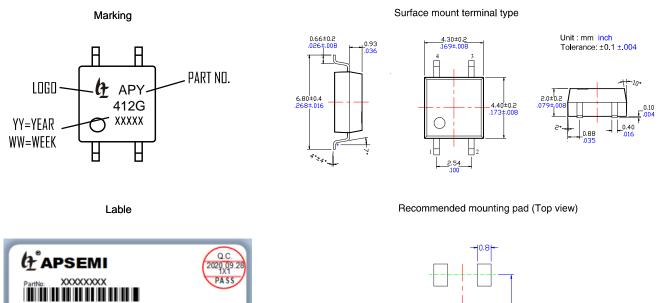




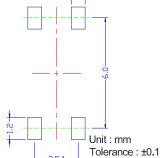




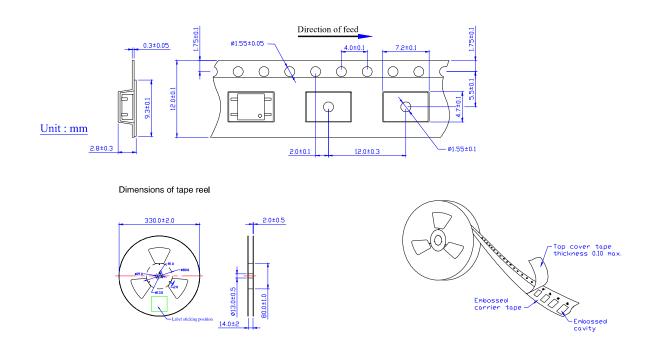
Dimensions and Package







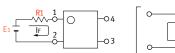
Tape dimensions

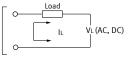




Using Methods

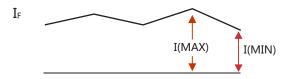
Examples of resistance value to control LED forward current (IF=5mA)





E1	R1 (Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



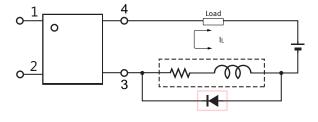
Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

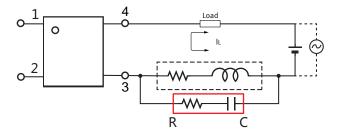
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	١ _F	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.



CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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